The influence of thermal annealing on the morphology and structural properties of a conjugated polymer in blends with an organic acceptor material

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ABSTRACT

In this report the influence of thermal annealing of thin P3HT films and P3HT:C_{60} composites were studied regarding their morphology and structural properties. Atomic force microscope measurements on P3HT films and P3HT:C_{60} composite disclose some variation in morphology during annealing due to the crystallization of C_{60}. The as-prepared P3HT:C_{60} films have a higher surface roughness and larger cluster size compared to the as-prepared P3HT films. The thermal annealing effects on the optical microscopy indicate that the polymer shows improved capability to self-organize. Their structural properties were studied by X-ray diffraction analysis. It was found that the crystallinity of the investigated films is drastically increased upon annealing. A decrease in grain sizes was observed for the blend which is due to a disordering of P3HT chains caused by an addition of C_{60} fullerene.

Keywords: poly(3-hexylthiophene), annealing, crystallinity, X-ray diffraction, high-resolution transmission electron microscopy

1. INTRODUCTION

Plastic solar cells consisting of an interpenetrating network of fullerenes and conjugated polymers have gained wide spread scientific interest during the last decade due to their low production cost and easy solution processing, low specific weight mechanically flexibility **[1-3]**. Currently, the best devices consist of a single bulk-heterojunction (BHJ) active layer, where the polymer (donor) and fullerene (acceptor) are deposited from a common solvent. As the solvent dries the donor and acceptor components separate into domains. The eventual efficiency of the solar cell has shown to be extremely sensitive to the size, morphology, composition, and the crystallinity of the formed domains **[4, 5]**.

Enhancement of the morphology in devices fabricated with a mixture of regio-regular poly(3-hexylthiophene) (P3HT) and [6,6]-phenyl C_{61}-butyric acid methyl ester (PCBM) has been observed with the use of heat-treatment methods **[3, 6]** resulting in solar cells with higher power efficiencies. The increase in solar cell efficiency can be explained by simultaneously increasing the optical absorption as well as the charge carrier mobilities, which are correlated to the enhanced crystallization of P3HT during annealing **[3]**. Aasmundtveit et al. **[7]** reported that polythiophenes tend to crystallize in pristine P3HT films. Recently, it was shown by electron diffraction that P3HT is also capable of a crystalline organisation in blends with methanofullerenes **[8]**. In this article, the influence of thermal annealing on the morphology and structural changes of P3HT were investigated. The morphological changes of the active layers were monitored using various techniques.

2.   EXPERIMENT DETAILS

2.1 Sample preparation

All the chemicals used in this experiment were purchased from Sigma Aldrich. Regio-regular poly (3-hexylthiophene) (rr-P3HT) was used as a light absorption and electron donating material; while fullerene (C_{60}) was used as an electron acceptor material. These materials were used as received, without any further purification. Indium tin oxide (ITO) coated on a 1 mm glass substrate with a resistance between 8 and 12 Ω/square, and silicon (Si) substrates were successfully cleaned with acetone and isopropyl alcohol and dried in dry nitrogen. A mixture of rr-P3HT (5 mg) and C_{60} (5 mg) was dissolved in 1mL of chloroform solution. The solution was stirred over night at a temperature of 50 $^{\circ}$C to maximise mixing of P3HT:C_{60} solution. P3HT and its blends with a thickness of about 100 nm were spin coated onto the Si substrates. The samples were dried on a hot plate at a temperature of 50 $^{\circ}$C for 15 min.

2.2 Characterization

A Tecnai F20 field emission high-resolution transmission electron microscope (HR-TEM), operated at 120 kV was employed to examine the internal structure and crystallinity of regio-regular P3HT. Specimens for HR-TEM analysis were prepared by dispersing the P3HT in chloroform, of which a drop was subsequently transferred to a holey-carbon copper grid and dried at ambient conditions. Atomic Force Microscopy (AFM) images of the top surface of thin films of regio-regular P3HT and its blends spin coated on Si

(110) substrates in a tapping mode were analysed using a Veeco AFM system (Digital Instruments) at ambient conditions. A Polarised Optical Microscope (Carl Zeiss axiovisson) was employed to study the optical morphology of the as-prepared P3HT films with that annealed at different temperatures for 30 min. Film thickness was measured using a Veeco DEKTAK 6M Stylus profilometer.

A Philips PW 1830 x-ray diffractometer with a Cu K_α (λ = 0.154 nm) monochromated radiation source, operating at 45.0 kV and 40.0 mA was utilized in order to determine the crystallinity of P3HT film and its blends spin coated onto a Si substrate. XRD data were collected in the 2θ ranging from 3° to 40° with a step size of 0.02°. The grain sizes of the films were calculated using the Scherer formula.

3. RESULTS AND DISCUSSION

3.1. Atomic force microscopy measurements

The morphology of the polymer/acceptor composite or photoactive layers, that play a key role in the final solar cell performance, can be strongly modified and improved by thermal annealing. The surface topography obtained from an atomic force microscope (AFM) usually gives a good insight into the film formation ability and the tendency of the components to phase separate. Figure 1 shows a series of AFM images of the P3HT and its blends obtained in tapping mode. The surface of the as-prepared P3HT on a Si

substrate and P3HT:C_{60} (1:1 wt. %) films is very smooth with a root mean square (rms) roughness (σ_{rms}) of 1.375 and 1.679 nm, respectively. The film does not show any coarse separation into different phases. The P3HT:C_{60} (1:1 wt. %) film (Fig. 1 d) shows a higher surface roughness, which is probably due to the addition of the fullerene (C_{60}).

However, upon annealing at 110 ºC for 30 min (Fig. 1 b) the surface roughness of P3HT increases up to 7.89 nm, while P3HT:C_{60} (1:1 wt. %) film (Fig. 1 e) show a pronounced surface roughness of about 18.90 nm. When the samples were annealed at 150 ºC, the surface roughness increased up to 8.25 and 19.31 nm for P3HT and the blend, respectively. It is evident in Figure 1 that the annealed samples show a much coarser texture with broad "hill-like" features compared with the as-prepared samples. The rough surface is probably a signature of polymer reorganization, which in turn enhances ordered structure formation in the thin film and also increases the carrier mobility which could produce a higher efficiency from the devices. This suggests that there is a thermodynamic driving force for the sample to reorganize towards a more stable equilibrium and thus to phase separate. However, excessive roughness makes phase segregation excessively comparable to the exciton diffusion length, which leads to the reduced charge segregation and device efficiencies. Similar results were also observed by Li et al. [9] and Huang-Zhong et al. [10]. Recent morphological and structural studies have shown that in P3HT:PCBM active layers the crystallization and the demixing are interdependent parameters [8].
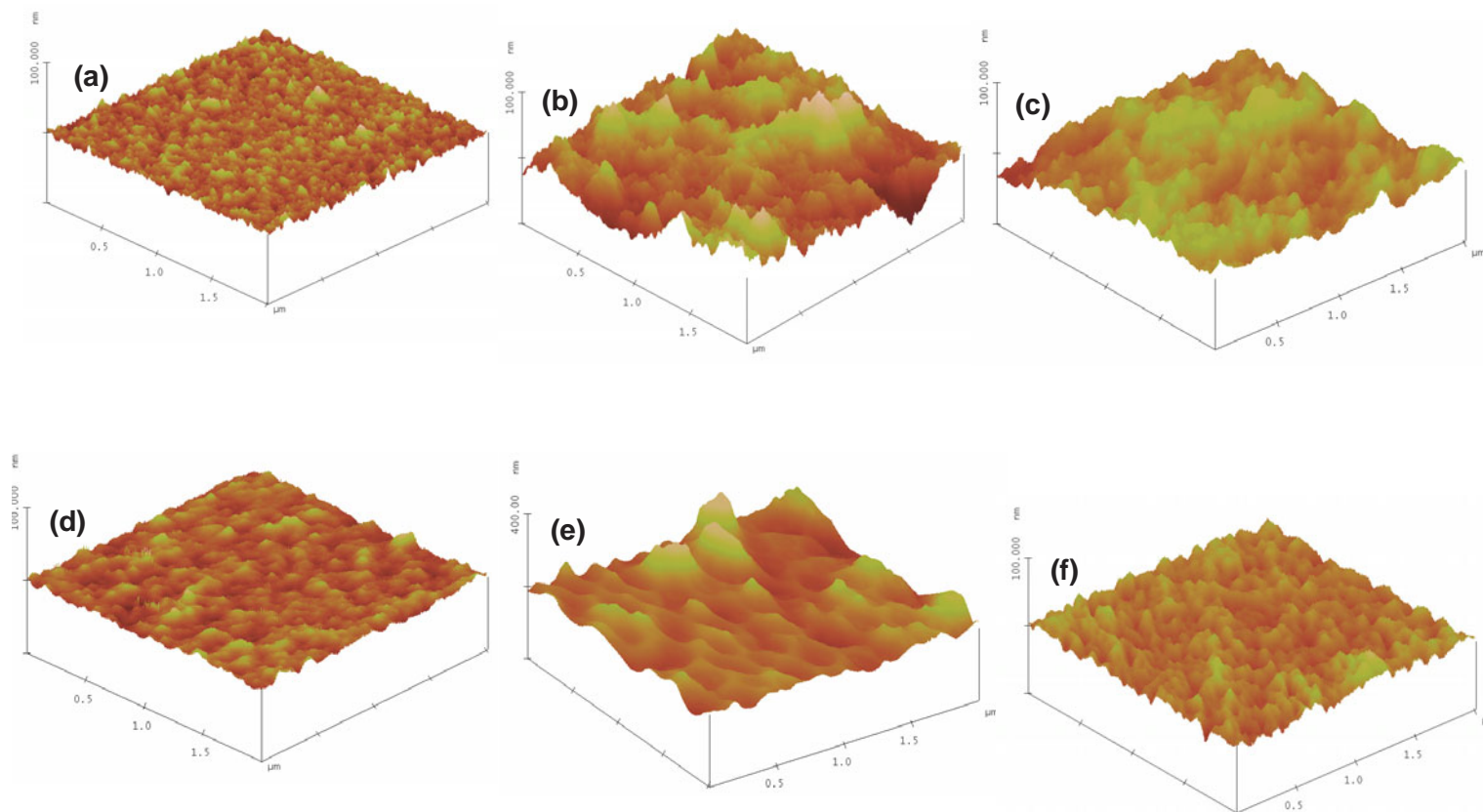
Figure 1: AFM height images of the surface of the active layer consisting of (a) as-prepared pure P3HT, (b) annealed at 110 ⁰C, (c) annealed at 150 ⁰C, (d) as-prepared P3HT:C_{60} (1:1 wt. %), (e) P3HT:C_{60} (1:1 wt. %) annealed at 110 ⁰C, and (f) annealed at 150 ⁰C. Note all the samples were annealed for 30 min.

3.2. Transmission electron microscopy measurements

The HR-TEM micrograph presented in Figure 2 illustrates that the rr-P3HT are crystalline. The micrograph shows a homogeneous layer without any obvious phase separation. The inset in Fig. 2 corresponds to the fast Fourier transform (FFT) of the selected area. The FFT shows a very low crystallinity of P3HT indicating that P3HT material is composed of an amorphous polymer matrix with crystalline regions (circled in Fig. 2) which possess a spacing of ~ 0.8 ± 0.06 nm, corresponding to the (200) planes. Drees et al. [11] also reported a bright field TEM image of P3HT showing a large and extended disordered (amorphous) zone between the crystalline lamellae.
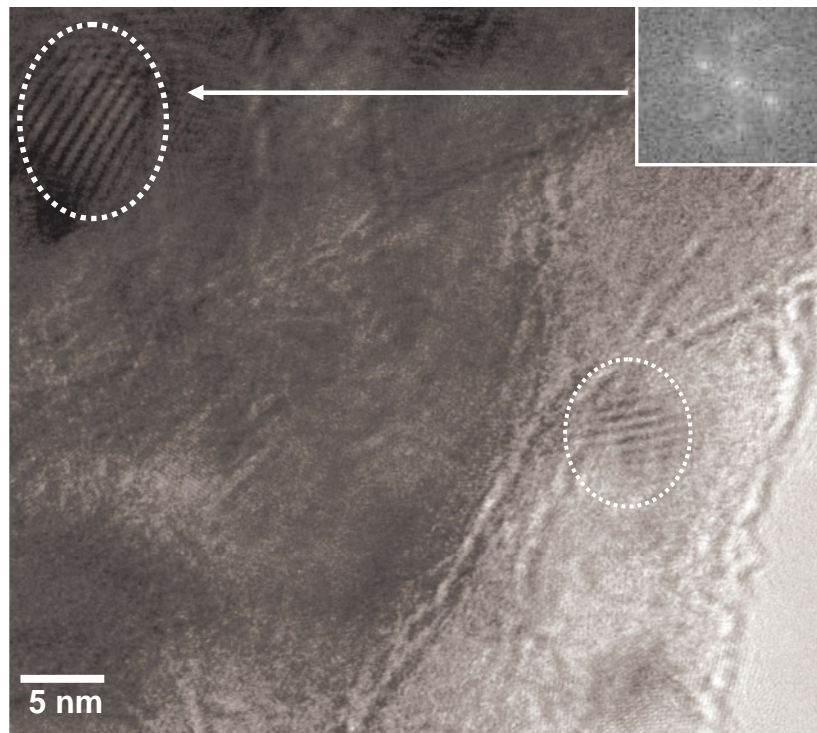

5 nm

Figure 2: HR-TEM micrograph of the rr-P3HT film and the corresponding fast Fourier transform (FFT) of the selected area (inset).

3.3. Optical microscopy measurements

Polarized optical microscopy micrographs of as-prepared P3HT films and P3HT:C_{60} (1:1 wt. %) blends compared with that annealed at 110 ºC and 150 ºC for 30 min are shown in Figure 3. It is evident in Figure 3(a) that the as-prepared P3HT film is relatively smooth with tarnishes (small stains). When these films are annealed their optical contrast changes, the film becomes rougher and agglomerations of the films are observed. These changes in the optical micrographs are due to the annealing, indicating an enhancement in the crystallinity of the P3HT films.

Moreover, when P3HT sample was blended with a C_{60} fullerene, P3HT:C_{60} (1:1 wt. %) ratio (fig. 3(d)), the as-prepared blend film showed an irregular behaviour and with larger agglomeration (spheres) as compared to as-prepared and annealed P3HT film. These agglomerations (or spheres) are probably linked to C_{60}. However, when the blend is annealed, the spheres become bigger and show an increase in coarseness. The clustering of the spheres is probably due to a diffusion of C_{60} into P3HT during annealing. This is in good agreement with results obtained by the AFM technique. Campoy-Quiles et al. [12] observed colour visible changes during a continuous heating cycle of P3HT. They also showed that these visible colour changes may correspond to P3HT crystallization which is then followed by melting of the material.
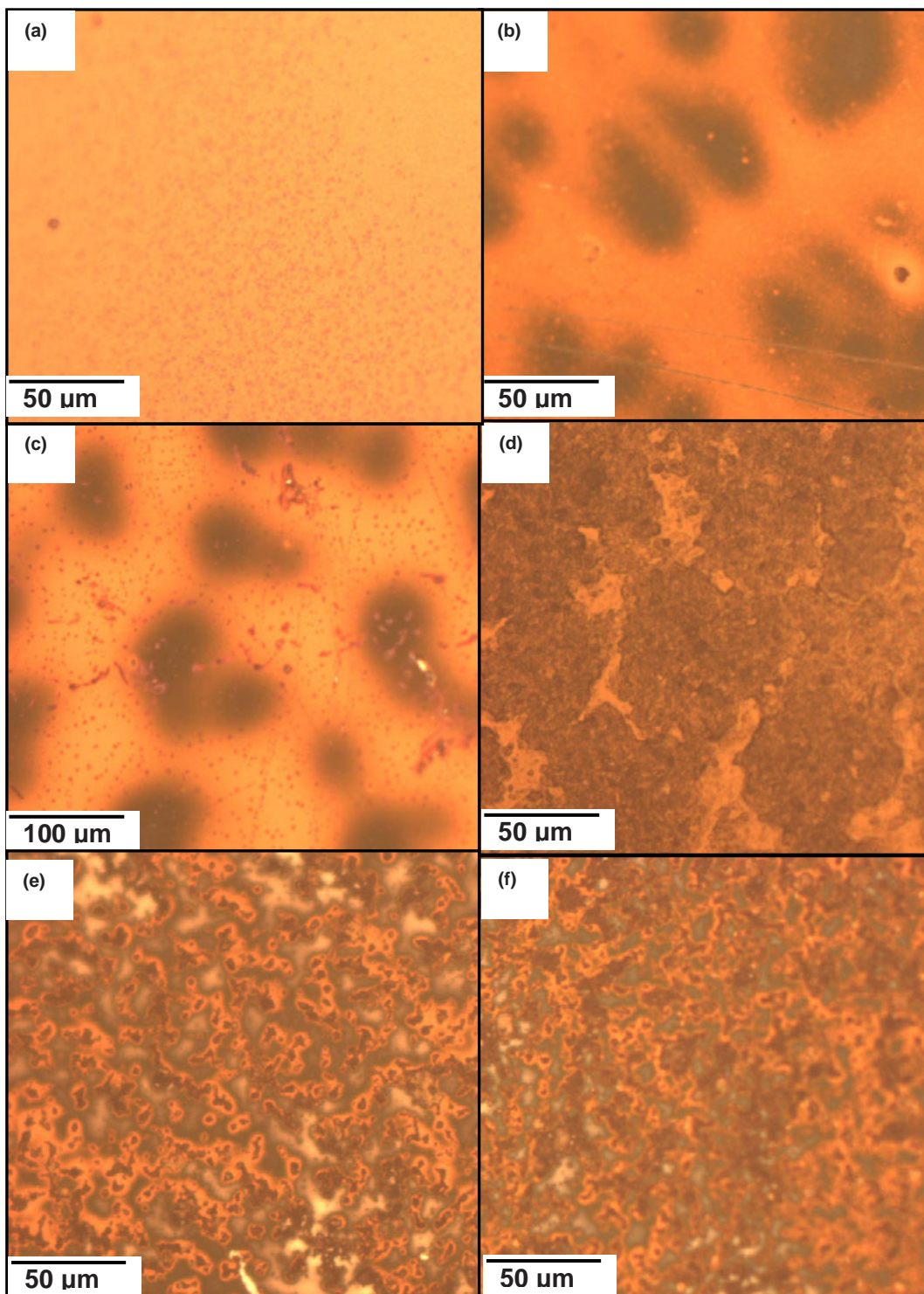
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Figure 3: Optical microscopy images of (a) as-prepared P3HT (b) P3HT film annealed at 110 ºC, (c) P3HT film annealed at 150 ºC, (d) as-prepared P3HT:C_{60} (1:1 wt. %) blend, (e) annealed blend at 110 ºC, and (f) annealed blend at 150 ºC. Note all the samples were annealed for 30 min

3.4. X-ray diffraction measurements

For a detailed study of the structural ordering of rr-P3HT, an XRD diffraction technique was used. Additionally, the changes upon thermal annealing of the films for 30 min at different temperatures were analysed. Figure 4 shows the XRD spectra of the as-prepared P3HT films and it blends P3HT: C_{60} (1:1 wt. %) compared with that annealed at 110 and 150 °C for 30 min, respectively. The as-prepared sample shows a single diffraction peak before annealing at $2\theta = 5.4°$ which is associated with the lamella structure of thiophene rings in P3HT [13]. Upon annealing, the sample shows a secondary peak (200) at 10.8° and tertiary peak (300) at 15.9° indicating that all pristine P3HT films show a well-organized intraplane structure. The diffraction patterns of Figure 4 correspond to as describe by the JCPDS {48-2040}. The peak indicated by the arrow at about 28. 1° is associated with the Si substrate. However, the blend in Figure 4(b) showed a (220), (311), (222) and (331) diffraction peaks at 17.7, 20.9, 21.7 and 27.4° upon annealing at 150 °C, which are associated with a C_{60} fullerene as describe by the JCPDS {47-0787, 44-0558}. The corresponding lattice constant d, can be calculated using Bragg's law:

$$2\mathrm{d}\sin(\theta) = n\lambda \qquad (1)$$

where $\lambda = 0.154$ nm is the wavelength of incident beam, 2θ is the angle between incident and scattered X-ray wave vectors and n is the interference order.
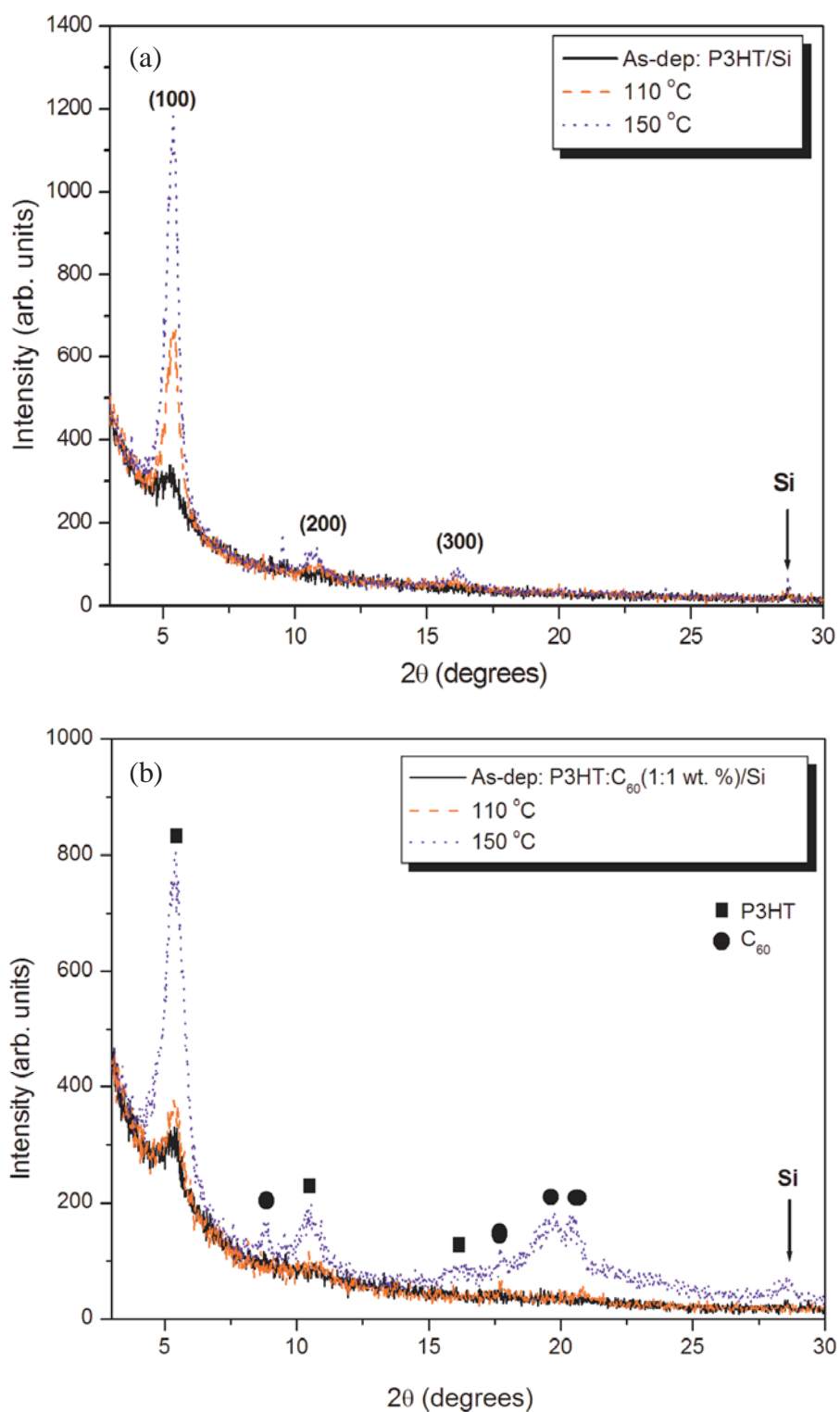
Figure 4: XRD patterns of as-prepared and annealed (a) rr-P3HT film and its blend (b) P3HT: C_{60} (1:1 wt. %) at 110 ºC and 150 ºC for 30 min. The P3HT peaks are indicated by a square and C_{60} by a circle.

Therefore, using equation (1), we obtain d = 1.64 ± 0.05 nm, 0.82 ± 0.05 nm and 0.56 ± 0.05 nm. The 0.82 nm spacing is similar to the d-spacing found in the TEM results. The detected peak originates from the P3HT crystallites with *a*-axis orientation (polymer backbone parallel and side chains perpendicular to the substrate **[14].** However, no diffraction peaks corresponding to the P3HT crystallites with other orientations such as polymer backbone and side chains parallel to the substrate were observed **[15]**. The mean sizes of the P3HT crystallites at (100) reflection L_{100} can be obtained using Scherrer's relation: **[16, 17].**

$$L = \frac{0.9\lambda}{B_{2\theta}\cos(\theta)} \qquad (2)$$

where λ is the wavelength of the x-rays, $B_{2\theta}$ is the full width at half maximum intensity FWHM) and θ is the diffraction angle. Therefore employing Scherer formula (2) we obtain the grain size L of P3HT and P3HT:C_{60} films at different annealing temperatures as shown in table 1.

As shown in Figure 4 and table 1, the emergence of a crystalline phase in the as-prepared samples is observed which are in good agreement with the HR-TEM results. This crystalline phase becomes more pronounced at a temperature of 150 °C. A minimum grain size of 12 nm is found in the as-prepared P3HT sample. At around 150 °C the grain size growth is well increased. This indicates an increase in the ordering of the alkyl chains within the main thiophene chains. However, when a P3HT is blended with C_{60} fullerene (1:1 wt. %), the full width at half maximum (FWHM) of P3HT at 5.4°

increases with the annealing temperature. The increase in a FWHM (reduction in grain sizes) as well a slight decrease in P3HT crystallites is due to a disordering of P3HT chains caused by an addition of C_{60} fullerene. This can also be due to a diffusion of C_{60} molecules forming larger clusters leading to a phase separation of P3HT and C_{60}.

Table 1: Grain size of P3HT and P3HT:C_{60} (1:1 wt. %) films for different annealing temperatures.

	P3HT Film			**P3HT:C_{60} Composite Film**		
Temperature (°C)	RT	110	150	RT	110	150
Grain Size (nm)	12.2	13.4	15.9	17.2	14.7	12.1

Kline et al. **[18]** reported that films of higher molecular weight P3HT produces a broader XRD peak suggesting a more disordered film with smaller crystalline domains. The authors argue that the smaller π-stacked domains, connected by disordered polymer chains, would enable easier charge transport through the film and prevent charge trapping within crystalline domains or at grain boundaries. Chuo et al. **[19]** showed that when P3HT is blended with PCBM, the P3HT crystallite size reduces with an increase in annealing temperature and resulted in an increase in the short circuit current density (J_{sc}). They also showed that the particles of PCBM become larger and subsequently lead to better pathways for electron transport. It should be

noted, that the obtained values correspond to the domain size along the a-axis and that no crystal with b- or c-axis orientation was detected. Similar results on d-spacing were reported by Kim et al. [20] and Erb et al. [15].

4. CONCLUSION

In conclusion, we have studied the morphology and structural properties of P3HT films and P3HT:C_{60} composite films both as-prepared and annealed at different temperatures. AFM measurements showed that the blends have a higher surface roughness compared to the pure P3HT films. After annealing, the surface roughness of pure P3HT and P3HT:C_{60} (1:1 wt. %) film increased; this can be related to a signature of polymer reorganization, which in turn enhances ordered structure formation in the thin film. HR-TEM results showed a homogeneous layer of P3HT film without any obvious phase separation. The TEM studies also exhibited very low features of crystallization that indicates that it composed of an amorphous network with crystallites embedded in it. XRD studies have also demonstrated the crystalline nature of pure P3HT films. The as-prepared P3HT-films were found to be partially crystalline whereas the crystallinity increases as the temperature increases. In the case of the film annealed at 150 °C; a crystallite size of 15.9 nm was obtained from analysis of the X-ray diffraction pattern. A reduction in the grain sizes as well a slight decrease in P3HT crystallites were observed when a P3HT:C_{60} (1:1 wt. %), blended structure

were prepared. This is due to a disordering of P3HT chains caused by the addition of fullerene.

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